



Features

- Advanced Multiple Quantum Well (MQW) Fabry Perot (FP) Laser Design
- Low Distortion
 - o IMD3 typ. –57 dBc
- \Box RIN < -140 dB/Hz
- Cost-effective Uncooled Laser Technology
- 5.6-mm TO-style package with SMF pigtail

Applications

- □ Wireless (CDMA) fiber-optic repeaters
- Analog transmission

Description

The FP-1310-C5-2-A2-xx-A-x-x series of Multi - Quantum Well (MQW) Fabry Perot (FP) lasers have been designed specifically for analog applications, especially wireless repeater applications. The devices feature high output power, wide operating temperature range, low distortion characteristics, and low RIN noise.

Their uncooled, hermetically sealed, coaxial fiberpigtailed packages are a cost -effective means of providing a highly linear light source for intermediatereach and long -reach analog transmission applications.





FP-1310-C5-2-A2-xx-A-x-x

Absolute Maximum Ratings

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Parameter	Symbol	Condition	Min	Max	Unit			
Operating Case Temperature	T _c	I=I _{op}	-20	85	°C			
Storage Temperature	T _{stg}		-40	100	°C			
Laser Forward Current	I _f			120	mA			
Laser Reverse Bias	V _r			2	V			
Photodiode Reverse Bias	V_{rpd}			10	V			

Electrical and Optical Characteristics

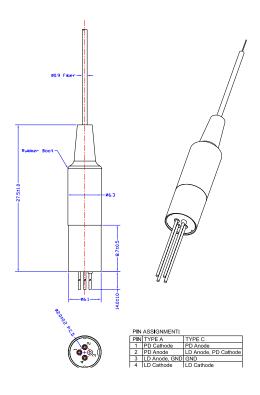
Parameters are at 25 °C unless otherwise noted.							
Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions	
Operating Temperature	Т	-20		85	°C		
Optical Output Power	Po	2.0			mW	CW	
Threshold Current	I _{th}		10 40	14 60	mA	T=25 °C T=85 °C	
Operating Current	I _{op}		25	35	mA	CW, P _o =2.0 mW, T=25 °C	
			35	60		CW, $P_0=2.0$ mW, $T=85$ °C	
Forward Voltage	V_F		1.1	1.6	V	P _o =2.0 mW	
Center Wavelength	λ_{c}	1270	1310	1350	nm	P _o =2.0 mW, CW	
RMS Spectral Width	Δλ		1.6	2.5	nm	P _o =2.0 mW	
Wavelength temperature coefficient	Δλ/ΔΤ		0.45	0.5	nm/°C		
Monitor Current	I _{mon}	25		375	μA/mW	V _{rpd} =5 V	
Monitor Dark Current	I _D			10	nA	V _{rpd} =5 V	
Tracking Error	γ	-1		1	dB	I_{mon} =const, γ =10 log (P_o /2.0) [dB]	
Optical Isolation*	ISO		30		dB		

^{*} Optical Isolation is only applicable to devices that include the optical isolator option.

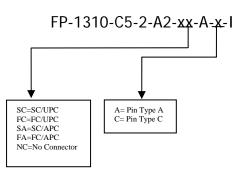
RF Characteristics

Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions
Relative Intensity Noise	RIN			-140	dB/Hz	CW,P _o =2.0 mW, f=50 MHz to 900 MHz
Third-Order Intermodulation	IMD3			-57	dBc	T=25 °C, P _o =2.0 mW, OMI=0.2, Two-tone test,936 MHz and 958 MHz
RF Bandpass Flatness	BF			1.0	dB	Peak to valley, 50 MHz to 1000 MHz

Dimensions (in mm)



Ordering Options



01-00-0028 REV 006



FP-1310-C5-2-A2-xx-A-x-x

Safety Information

All versions of this laser are Class 1M laser products per IEC* 60825-1:2001. Users should observe safety precautions such as those recommended by ANSI** Z136.1-2000, ANSI Z36.2-1997 and IEC 60825-1:2001.

This product does not conform to 21 CFR 1040.10 and 1040.11. Consequently, this laser module is only intended for use as a component by manufacturers of electronic products and equipment.

Wavelength = 1.3 µm Maximum Power = 75mW Single-mode fiber pigtail Fiber Numerical Aperture = 0.14

Labeling is not affixed to the laser module due to size constraints; rather, labeling is placed on the outside of the shipping box.

This product is not shipped with a power supply.

Caution: use of controls or adjustments or performance of procedures other than those specified herein may result in hazardous radiation exposure.



classified in accordance with IEC 60825-1: 2001-08

^{*}IEC is a registered trademark of the International Electrotechnical Commission

 $[\]ensuremath{^{\star\star}}\xspace$ ANSI is a registered trademark of the American National Standards Institute